

## DUAL OPERATIONAL AMPLIFIER

### DESCRIPTION

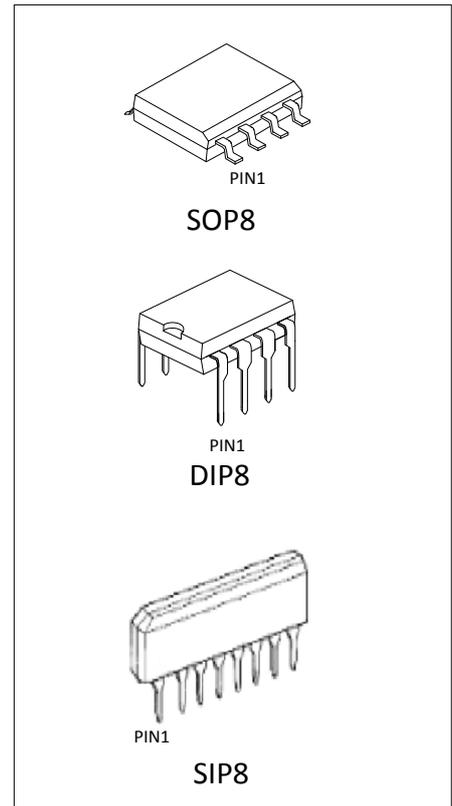
HG4580 is the dual operational amplifier, specially designed for improving the tone control, which is most suitable for the audio application.

Featuring noiseless, higher gain bandwidth, high output current and low distortion ratio, and it is most suitable not only for acoustic electronic part of audio pre-amp and active filter, but also for the industrial measurement tools. It is also suitable for the head phone amp at higher output current. And further more, it can be applied for the handy type set operational amplifier of general purpose in application of low voltage single supply type which is properly biased of the input low voltage source.

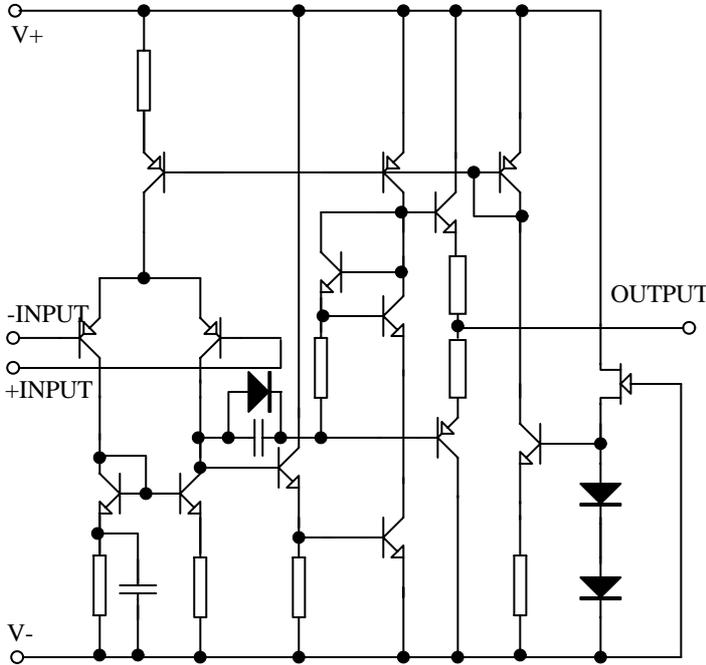
### FEATURE

- Operating Voltage                      ( $\pm 2V \sim \pm 16V$ )
- Low Input Noise Voltage            ( $0.8\mu V_{rms}$  Typ.)
- Wide Gain Bandwidth Product ( $15\text{mhz}$  Typ.)
- Low Distortion                        ( $0.0005\%$  Typ.)
- Slew Rate                                ( $5V/\mu A$  Typ.)
- Package Outline                        DIP8、SIP8、SOP8
- Bipolar Technology

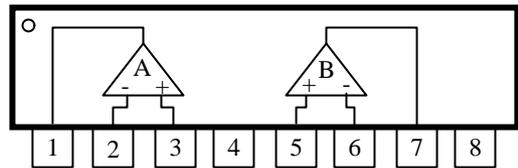
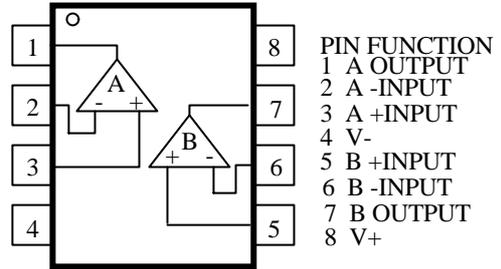
### Outline Drawing



**EQUIVALENT CIRCUIT**



**PIN CONFIGURATION**



**ABSOLUTE MAXIMUM RATINGS (Ta=25°C)**

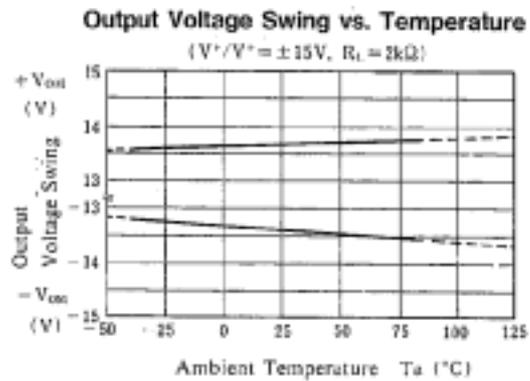
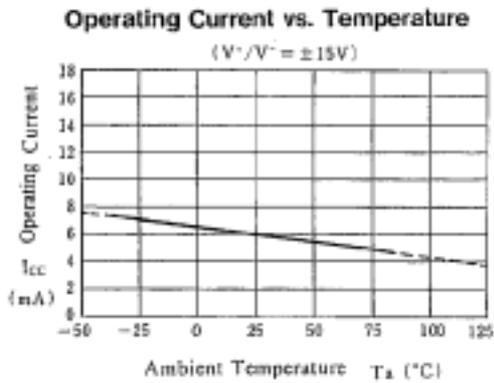
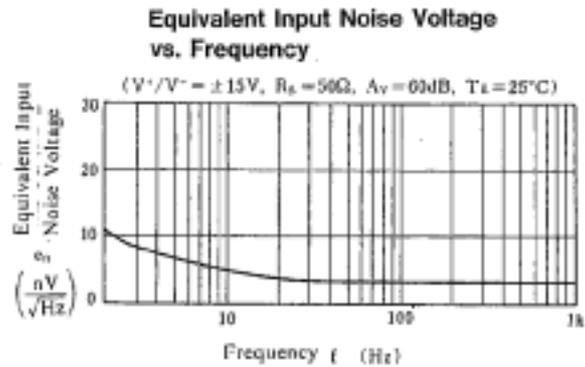
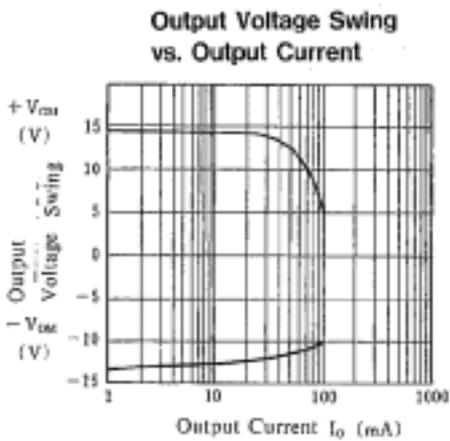
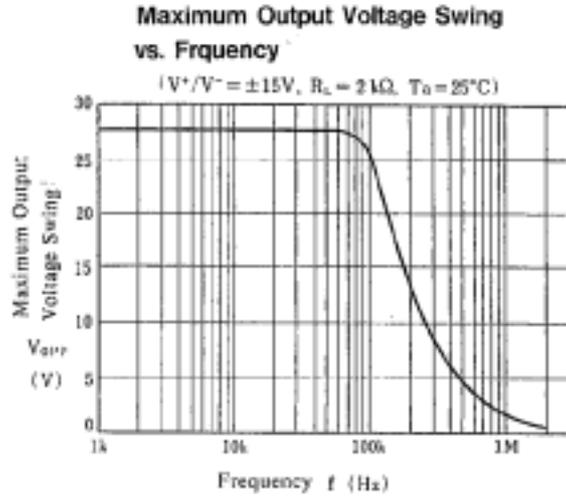
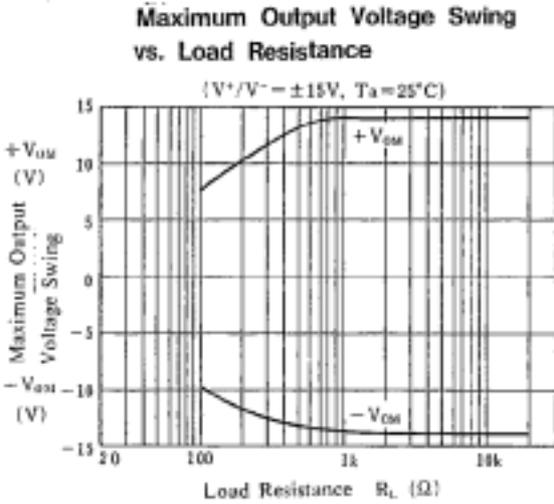
Characteristic	Symbol	Value	Unit
Supply Voltage	V+/V-	±16	V
Input Voltage	V <sub>IC</sub>	±15	V
Differential Input Voltage	V <sub>ID</sub>	±30	V
Output Current	I <sub>c</sub>	±50	mA
Power Dissipation	P <sub>d</sub>	800	mW
Operating Temperature Range	T <sub>amb</sub>	-40~85	°C
Storage Temperature Range	T <sub>stg</sub>	-40~125	°C

**ELECTRICAL CHARACTERISTICS**

(Unless otherwise specified: Ta=25°C, V+/V-=±15V)

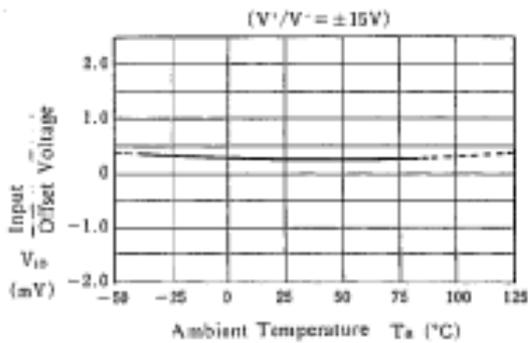
Parameter	Symbol	Test condition	Min	Typ	Max	Unit
Input Offset Voltage	V <sub>IO</sub>	R <sub>s</sub> ≤ 10kΩ		0.5	3	mV
Input Offset Current	I <sub>IO</sub>			5	200	nA
Input Bias Current	I <sub>B</sub>			100	500	nA
Large Signal Voltage Gain	A <sub>v</sub>	R <sub>L</sub> ≥ 2kΩ, V <sub>o</sub> =±10V	90	110		dB
Output Voltage Swing	V <sub>OM</sub>	R <sub>L</sub> ≥ 2kΩ	±12	±13.5		V
Input Common Mode Voltage Range	V <sub>ICM</sub>		±12	±13.5		V
Common Mode Rejection Ratio	CMR	R <sub>s</sub> ≤ 10kΩ	80	110		dB
Supply Voltage Rejection Ratio	SVR	R <sub>s</sub> ≤ 10kΩ	80	110		dB
Operating Current	I <sub>cc</sub>			6	9	mA
Slew Rate	SR	R <sub>L</sub> ≥ 2kΩ		5		V/μA
Gain Bandwidth Product	GB	f=10kHz		15		MHz
Total Harmonic Distortion	THD	A <sub>v</sub> =20dB, V <sub>o</sub> =5V, f=1kHz, R <sub>L</sub> =2kΩ		0.0005		%
Input Noise Voltage	V <sub>NI</sub>	RIAA R <sub>s</sub> =2.2kΩ, 30kHzLPF		0.8		μV <sub>rms</sub>

**CHARACTERISTICS CURVES**

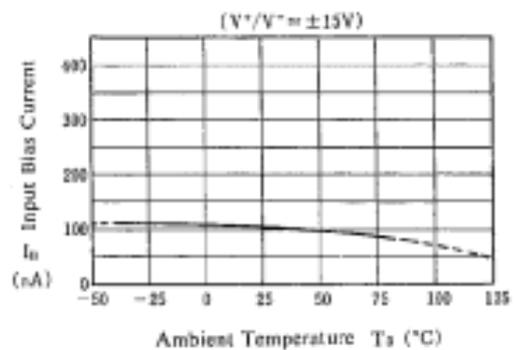


■ TYPICAL CHARACTERISTICS

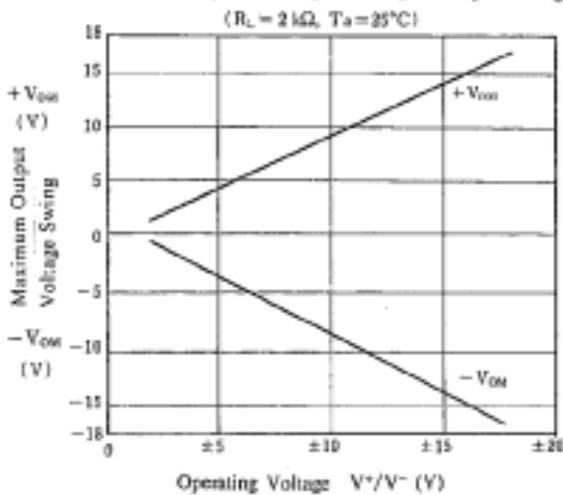
Input Offset Voltage vs. Temperature



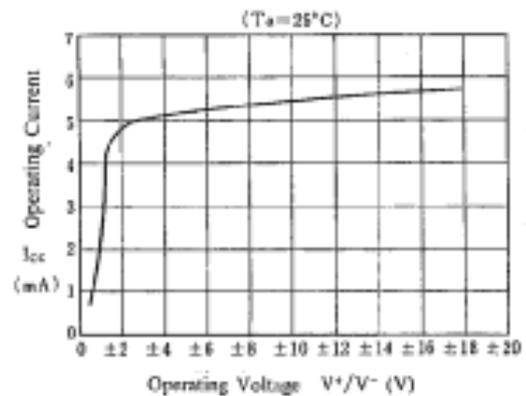
Input Bias Current vs. Temperature



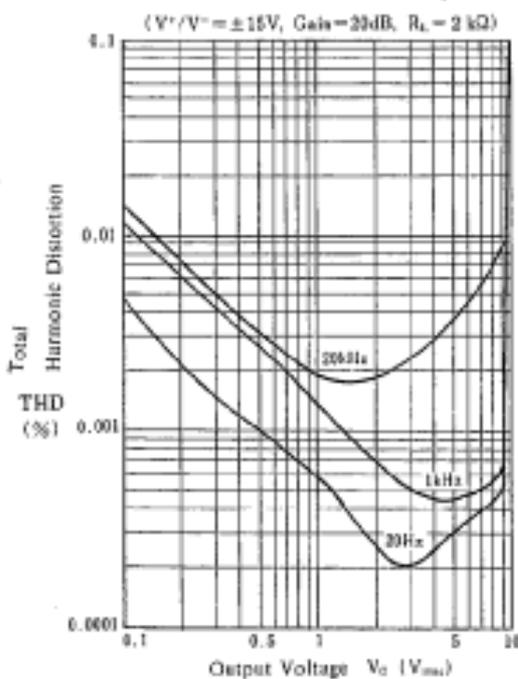
Maximum Output Voltage Swing vs. Operating Voltage



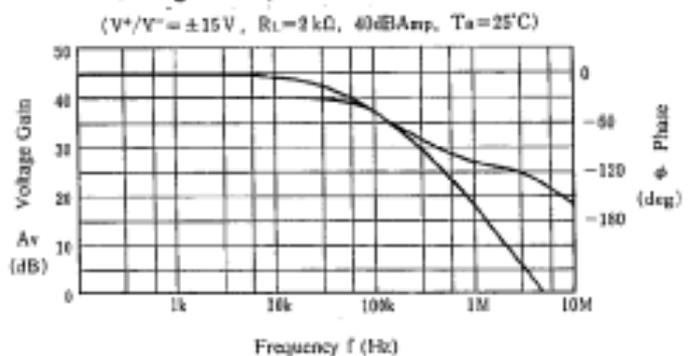
Operating Current vs. Operating Voltage



Total Harmonic Distortion vs. Output Voltage



Voltage Gain, Phase vs. Frequency



Important statement:

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